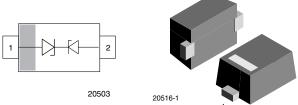
COMPLIANT

GREEN (5-2008)**



Vishay Semiconductors

Bidirectional Asymmetrical (BiAs) Single Line ESD-Protection Diode in SOD923

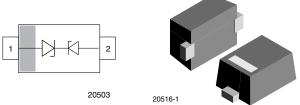


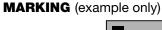
FEATURES

- Tiny SOD-923 package
- Package height < 0.4 mm
- Working range 7 V up to + 14 V or 14 V up to



- Low capacitance typical C_D = 8 pF
- ESD-protection acc. IEC 61000-4-2 ± 25 kV contact discharge ± 30 kV air discharge
- Working voltage range V_{RWM} = 5 V
- e3 Sn
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC







Bar = pin 1 marking Y = type code (see table below) X = date code

ORDERING INFORMATION						
DEVICE NAME	ORDERING CODE	TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL)	MINIMUM ORDER QUANTITY			
VCUT0714A-02Z	VCUT0714A-02Z-GS08	8000	8000			

PACKAGE DATA							
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS	
VCUT0714A-02Z	SOD-923	Α	0.45 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals	

ABSOLUTE MAXIMUM RATINGS VCUT0714A-02Z						
PARAMETER	TEST CONDITIONS	TEST CONDITIONS SYMBOL				
Peak pulse current	Pin 1 to pin 2 acc. IEC 61000-4-5, 8/20 µs/single shot		5	Α		
	Pin 2 to pin 1 acc. IEC 61000-4-5, 8/20 μs/single shot	І _{РРМ}	2	Α		
Peak pulse power	Pin 1 to pin 2 acc. IEC 61000-4-5, 8/20 µs/single shot	D	63	W		
	Pin 2 to pin 1 acc. IEC 61000-4-5, 8/20 µs/single shot	P _{PP}	54	W		
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	± 25	kV		
	Air discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV		
Operating temperature	Junction temperature	T _J - 40 to + 125		°C		
Storage temperature		T _{STG}	- 55 to + 150	°C		

^{**} Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

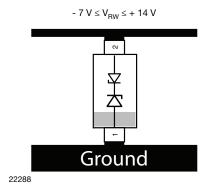
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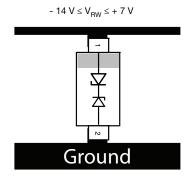
Bidirectional Asymmetrical (BiAs) Single Line ESD-Protection Diode in SOD923



CUT THE SPIKES WITH VCUT0714A-02Z

The VCUT0714A-02Z is a bidirectional but asymmetrical (BiAs) ESD-protection device which clamps positive and negative overvoltage transients to ground. Connected between the signal or data line and the ground the VCUT0714A-02Z offers a high isolation (low leakage current, small capacitance) within the specified working range of - 7 V to + 14 V or - 14 V and + 7 V. Due to the short leads and small package size of the tiny SOD-923 package the line inductance is very low, so that fast transients like an ESD-strike can be clamped with minimal over- or undershoots.





ELECTRICAL CHARACTERISTICS VCUT0714A-02Z							
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines	
Reverse working voltage	at I = 1 μA	V_{RWM}	14	-	-	V	
Reverse current	at V = 14 V	I _R	-	-	0.1	μΑ	
Reverse breakdown voltage	at I = 1 mA	V_{BR}	14.5	-	-	V	
Reverse clamping voltage	at I _{PP} = 1 A	V _C	-	-	27	V	
	at I _{PP} = I _{PPM} = 2 A		-	-	30	V	
Capacitance	at V = 0 V; f = 1 MHz	_	-	8	8.5	pF	
	at V = 7 V; f = 1 MHz	C _D	-	4	-	pF	

Note

Ratings at 25 °C, ambient temperature unless otherwise specified. Measured from pin 2 to pin 1.

ELECTRICAL CHARACTERISTICS VCUT0714A-02Z								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines		
Reverse working voltage	at I = 1 μA	V_{RWM}	7	-	-	V		
Reverse current	at V = 7 V	I _R	-	-	0.1	μA		
Reverse breakdown voltage	at I = 1 mA	V_{BR}	7.3	-	-	V		
Reverse clamping voltage	at I _{PP} = 1 A	V	-	-	13	V		
	at I _{PP} = I _{PPM} = 5 A	V _C	-	-	17	V		
Capacitance	at V = 0 V; f = 1 MHz	C _D	-	8	8.5	pF		
	at V = 3.5 V; f = 1 MHz		-	6.4	-	pF		

Note

• Ratings at 25 °C, ambient temperature unless otherwise specified. Measured from pin 1 to pin 2.



Bidirectional Asymmetrical (BiAs) Single Line ESD-Protection Diode in SOD923

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

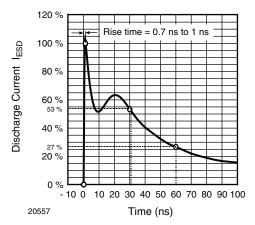


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330 Ω /150 pF)

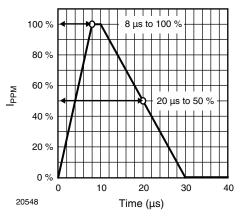


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

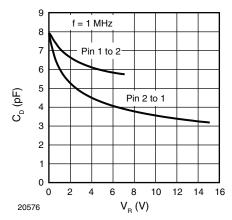


Fig. 3 - Typical Capacitance C_D vs. Reverse Voltage V_R

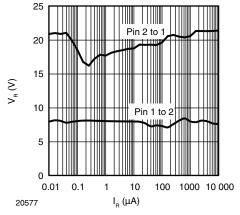


Fig. 4 - Typical Reverse Voltage V_{R} vs. Reverse Current I_{R}

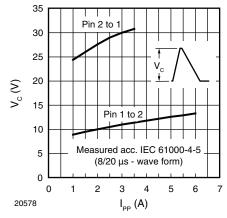


Fig. 5 - Typical Peak Clamping Voltage $V_{\rm C}$ vs. Peak Pulse Current $I_{\rm PP}$

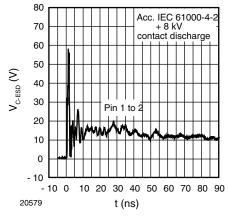


Fig. 6 - Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

Vishay Semiconductors

Bidirectional Asymmetrical (BiAs) Single Line ESD-Protection Diode in SOD923



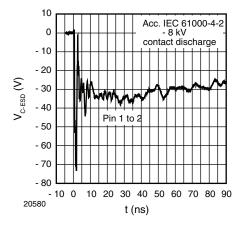


Fig. 7 - Typical Clamping Performance at - 8 kV Contact Discharge (acc. IEC 61000-4-2)

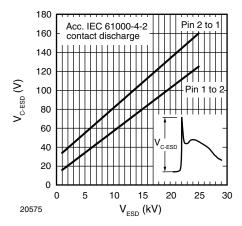
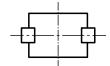
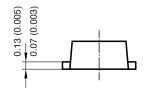
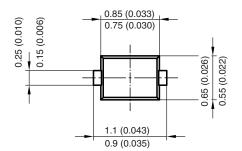


Fig. 8 - Typical Peak Clamping Voltage at ESD Contact Discharge (acc. IEC 61000-4-2)

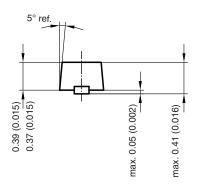
PACKAGE DIMENSIONS in millimeters (inches): SOD-923



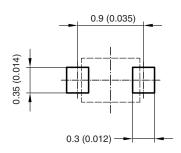




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Foot print recommendation:







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